VN2410L

Preferred Device

Small Signal MOSFET 200 mAmps, 240 Volts

N-Channel TO-92

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	240	Vdc
Drain-Gate Voltage	VDGR	60	Vdc
Gate–Source Voltage – Continuous – Non–repetitive (t _p ≤ 50 μs)	V _{GS} V _{GSM}	± 20 ± 40	Vdc Vpk
Continuous Drain Current	ID	200	mAdc
Pulsed Drain Current	I _{DM}	500	mAdc
Power Dissipation @ T _C = 25°C Derate above 25°C	PD	350 2.8	mW mW/°C
Operating and Storage Temperature	TJ, T _{Stg}	_	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	312.5	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/16" from case for 10 seconds	TL	300	°C

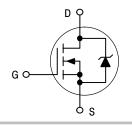


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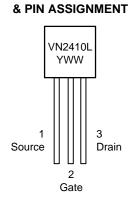
http://onsemi.com

200 mAMPS 60 VOLTS RDS(on) = 10 Ω

N-Channel







Y = Year WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping		
VN2410L	TO-92	1000 Units/Box		
VN2410LZL1	TO-92	2000 Ammo Pack		

Preferred devices are recommended choices for future use and best overall value.

VN2410L

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)

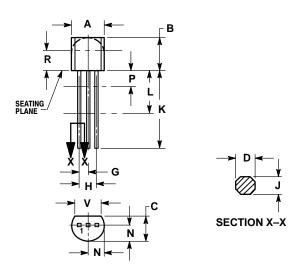
	Symbol	Min	Max	Unit	
STATIC CHARACTERISTICS	1			•	•
Drain-Source Breakdown Voltag (VGS = 0, I _D = 100 μA)	V _(BR) DSS	240	_	Vdc	
Zero Gate Voltage Drain Current (VDS = 120 Vdc, VGS = 0) (VDS = 120 Vdc, VGS = 0, TA = 125°C)		IDSS	- -	10 500	μAdc
Gate- Body Leakage (V _{DS} = 0, V _{GS} = ±15 V)	I _{GSS}	-	±100	nAdc	
Gate Threshold Voltage (V _{DS} = V _{GS} , I _D = 1.0 mA)	VGS(th)	0.8	2.0	Vdc	
On–State Drain Current (Note 1. $(V_{GS} = 10 \text{ V}, V_{DS} \ge 2.0 \text{ V}_{DS})$	I _{D(on)}	1.0	_	Adc	
Drain–Source On Resistance (Note 1.) ($V_{GS} = 2.5 \text{ V}, I_D = 0.1 \text{ A}$) ($V_{GS} = 10 \text{ V}, I_D = 0.5 \text{ A}$)		r _{DS(on)}	- -	10 10	Ω
Forward Transconductance (Note 1.) (V _{DS} = 10 V, I _D = 0.5 A)		9fs	300	_	mS
DYNAMIC CHARACTERISTI	cs	-		•	
Input Capacitance		C _{iss}	-	125	pF
Output Capacitance	(V _{DS} = 25 Vdc, V _{GS} = 0, f = 1.0 MHz)	C _{oss}	-	50	pF
Reverse Transfer Capacitance	,	C _{rss}	-	20	pF
SWITCHING CHARACTERIS	TICS	<u> </u>			
Turn-On Time		t(on)	-	8.0	ns
	$(V_{DD} = 60 \text{ Vdc}, I_{D} = 0.4 \text{ A},$ $R_{L} = 150 \Omega, R_{G} = 25 \Omega)$	t _(r)	-	8.0	ns
Turn-Off Time		t(off)	-	23	ns
		t _(f)	_	34	ns

^{1.} Pulse Test; Pulse Width < 300 μ s, Duty Cycle \leq 2.0%.

VN2410L

PACKAGE DIMENSIONS

TO-92 CASE 29-11 ISSUE AL



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Н	0.095	0.105	2.42	2.66	
J	0.015	0.020	0.39	0.50	
K	0.500		12.70		
L	0.250		6.35		
N	0.080	0.105	2.04	2.66	
Р		0.100		2.54	
R	0.115		2.93		
V	0 135		3 43		

STYLE 22:
PIN 1. SOURCE
2. GATE
3. DRAIN

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